Docket No.: 245402007300

Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF

MANUFACTURING THE SAME

Page 1 of 6

FIG.1

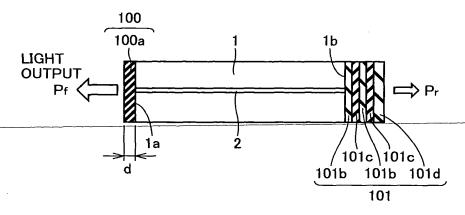


FIG.2

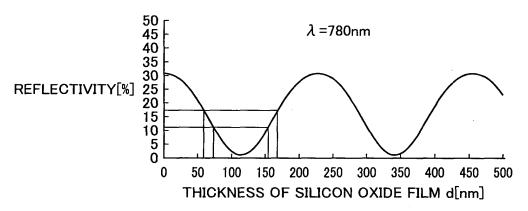
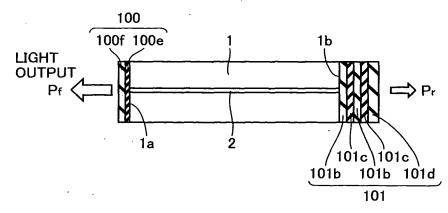


FIG.3



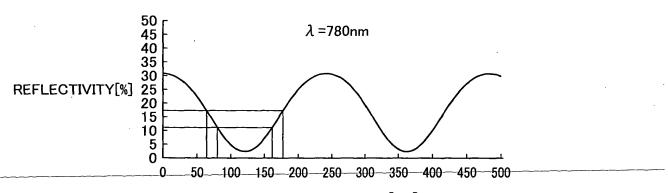
Docket No.: 245402007300

Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF

MANUFACTURING THE SAME

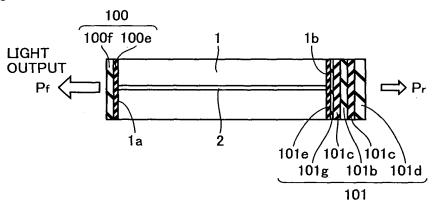
Page 2 of 6

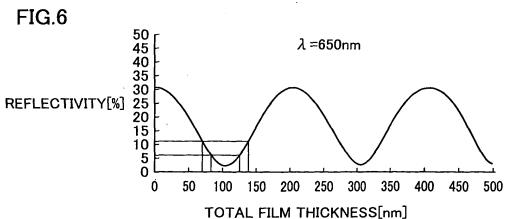
FIG.4



TOTAL FILM THICKNESS[nm]
(FIRST LAYER [SILICON OXIDE FILM 10nm] + SECOND LAYER [ALUMINA FILM])

FIG.5





(FIRST LAYER [SILICON OXIDE FILM 10nm] + SECOND LAYER [ALUMINA FILM])

Docket No.: 245402007300

Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF

MANUFACTURING THE SAME

Page 3 of 6

FIG.7 PRIOR ART

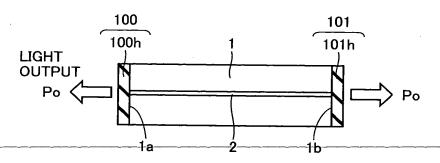


FIG.8 PRIOR ART

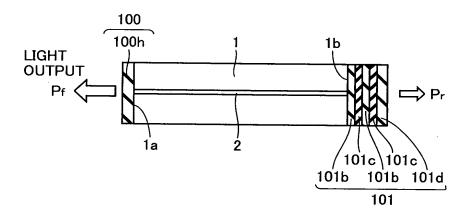
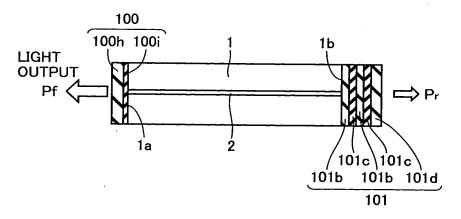


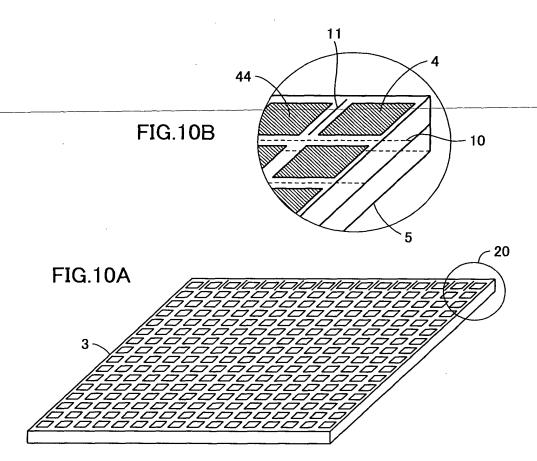
FIG.9 PRIOR ART



Docket No.: 245402007300

App No.: Not Yet Assigned Docket No.: 24540200730
Inventor: Makoto YOKOTA
Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF
MANUFACTURING THE SAME

Page 4 of 6



App No.: Not Yet Assigned Docket No.: 2454020073
Inventor: Makoto YOKOTA
Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF

Docket No.: 245402007300

MANUFACTURING THE SAME

Page 5 of 6

FIG.11

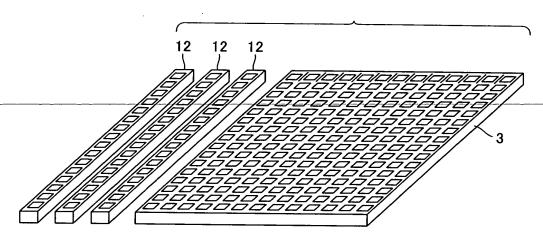
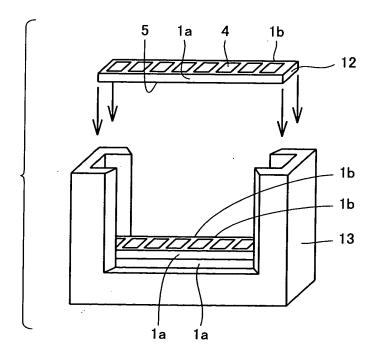


FIG.12



Docket No.: 245402007300

Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME

Page 6 of 6

FIG.13

